WDW

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ESC Asia

MPPT Interleaved Boost Converter

Description

The MPPT (Maximum power point tracking) Interleaved Boost Converter is for PV (Photovoltaic) applications reference design. Which is an Interleaved Booster circuit with digital controlled MPPT algorithm for the Solar Power System Applications. It operates at high switching frequency with Silicon Carbide (SiC) MOSFET to achieve low power losses, high efficiency, and reduction of size & weight.

Advantages

High output power (10kW Max. for 2 rails, 5kW per rail); Digital control MPPT algorithm (Perturb & Observe algorithm; P&O Method) for solar power application, reliable and not dependent on the panel properties and characteristics.

Features

- DC/DC Interleaved Booster Topology
- Max. Output Power: 10kW for 2 rails, 5kW per rail
- Solar Input Voltage: 150Vdc to 550Vdc
- DC Output Voltage: 600Vdc to 800Vdc
- Efficiency: Not measured

Core Chip

- MCU control: TI TMS320F28379D
- SiC MOSFET: Wolfspeed C3M0075120K
- SiC Diode: Wolfspeed C4D20120D
- Isolated gate driver: Infineon 1EDN7550B
- Current Sensor: ALLEGRO MICROSYSTEMS ACS37002LMABTR-050U5
- Isolated Power Module: Murata MGJ2D121503SC
- Isolated CAN Transceivers: CHIPANALOG CA-IS3062W
- Varistor: **TDK/EPCOS** B72214P2461K101
- HV Capacitors: Kemet C4AQQBW5300A3MJ, C4AQCBW5550A3MJ, ALA7DA301DF600
- Power Inductor: knitter-switch ICSC97430700LHS61, ICSI36430700LVK61

Applications

- Solar power system power conversion
- PV inverter
- PV power optimizer

Block Diagram









MPPT